

## NPN General Purpose Amplifier

This device is designed for use as general purpose amplifiers and switches requiring collector currents to 300 mA ．Sourced from Process 10．See PN100A for characteristics．

## Absolute Maximum Ratings＊

$\mathrm{TA}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter | Value | Units |
| :--- | :--- | :---: | :---: |
| $\mathrm{V}_{\text {CEO }}$ | Collector－Emitter Voltage | 25 | V |
| $\mathrm{~V}_{\text {CBO }}$ | Collector－Base Voltage | 25 | V |
| $\mathrm{~V}_{\text {EBO }}$ | Emitter－Base Voltage | 5.0 | V |
| $\mathrm{I}_{\mathrm{C}}$ | Collector Current－Continuous | 500 | mA |
| $\mathrm{~T}_{\mathrm{J}}, \mathrm{T}_{\mathrm{Stg}}$ | Operating and Storage Junction Temperature Range | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

＊These ratings are limiting values above which the serviceability of any semiconductor device may be impaired．
NOTES：
1）These ratings are based on a maximum junction temperature of 150 degrees $C$
2）These are steady state limits．The factory should be consulted on applications involving pulsed or low duty cycle operations．

Thermal Characteristics
$\mathrm{TA}=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Characteristic | Max | Units |
| :--- | :---: | :---: | :---: |
|  |  |  |  |
| $\mathrm{P}_{\mathrm{D}}$ | Total Device Dissipation | 625 | mW |
|  | Derate above $25^{\circ} \mathrm{C}$ | 5.0 | $\mathrm{~mW} /{ }^{\circ} \mathrm{C}$ |
| $\mathrm{R}_{\text {өJC }}$ | Thermal Resistance，Junction to Case | 83.3 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| $\mathrm{R}_{\text {өJA }}$ | Thermal Resistance，Junction to Ambient | 200 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Electrical Characteristics $\quad T A=25^{\circ} \mathrm{C}$ unless otherwise noted

| Symbol | Parameter | Test Conditions | Min | Max | Units |
| :--- | :---: | :---: | :---: | :---: | :---: |

OFF CHARACTERISTICS

| $\mathrm{V}_{\text {(BR)CEO }}$ | Collector-Emitter Breakdown <br> Voltage $^{*}$ | $\mathrm{I}_{\mathrm{C}}=10 \mathrm{~mA}, \mathrm{I}_{\mathrm{B}}=0$ | 25 | V |  |
| :--- | :--- | :--- | :---: | :---: | :---: |
| $\mathrm{~V}_{(\text {BR })} \mathrm{CBO}$ | Collector-Base Breakdown Voltage | $\mathrm{I}_{\mathrm{C}}=10 \mu \mathrm{~A}, \mathrm{I}_{\mathrm{E}}=0$ | 25 |  | V |
| $\mathrm{~V}_{\text {(BR)EBO }}$ | Emitter-Base Breakdown Voltage | $\mathrm{I}_{\mathrm{E}}=10 \mu \mathrm{I}, \mathrm{I}_{\mathrm{C}}=0$ | 5.0 |  | V |
| $\mathrm{I}_{\text {CBO }}$ | Collector-Cutoff Current | $\mathrm{V}_{\mathrm{CB}}=18 \mathrm{~V}, \mathrm{I}_{\mathrm{E}}=0$ |  | 100 | nA |
| $\mathrm{I}_{\text {EBO }}$ | Emitter-Cutoff Current | $\mathrm{V}_{\mathrm{EB}}=5.0 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=0$ |  | 100 | nA |

ON CHARACTERISTICS*

| $\mathrm{h}_{\mathrm{FE}}$ | DC Current Gain | $\mathrm{V}_{\mathrm{CE}}=4.5 \mathrm{~V}, \mathrm{IC}=2.0 \mathrm{~mA}$ |  |  |  |
| :--- | :--- | :--- | :--- | :--- | :--- |
|  |  | 2N3390 | 400 | 800 |  |
|  |  | 2N3391/A | 250 | 500 |  |
|  |  | 2N3392 | 150 | 300 |  |
|  |  | 2N3393 | 90 | 180 |  |

SMALL SIGNAL CHARACTERISTICS

| $\mathrm{C}_{\text {ob }}$ | Output Capacitance | $\mathrm{V}_{\mathrm{CB}}=10 \mathrm{~V}, \mathrm{f}=1.0 \mathrm{MHz}$ | 2.0 | 10 | pF |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{hf}_{\text {fe }}$ | Small-Signal Current Gain | $\mathrm{I} \mathrm{C}=2.0 \mathrm{~mA}, \mathrm{~V}_{\mathrm{CE}}=4.5 \mathrm{~V}$,  <br> $\mathrm{f}=1.0 \mathrm{kHz}$ 2N3390 <br>  2N3391/A <br>  2N3392 <br>  2N3393 | $\begin{gathered} 400 \\ 250 \\ 150 \\ 90 \\ \hline \end{gathered}$ | $\begin{array}{r} 1250 \\ 800 \\ 500 \\ 400 \\ \hline \end{array}$ |  |
| NF | Noise Figure | $\begin{aligned} & \mathrm{V}_{\mathrm{CE}}=4.5 \mathrm{~V}, \mathrm{I}_{\mathrm{C}}=100 \mu \mathrm{~A}, \\ & \mathrm{R}_{\mathrm{G}}=500 \Omega \Omega, \quad 2 \mathrm{~N} 3391 \mathrm{~A} \text { only } \\ & \mathrm{B}_{\mathrm{W}}=15.7 \mathrm{kHz} \\ & \hline \end{aligned}$ |  | 5.0 | dB |

*Pulse Test: Pulse Width $\leq 300 \mu \mathrm{~s}$, Duty Cycle $\leq 2.0 \%$

## TO-92 Tape and Reel Data

## TO-92 Packaging

Configuration: Figure 1.0
TO-92 TNR/AMMO PACKING INFROMATION

| Packing | Style | Quantity | EOL code |
| :---: | :---: | :---: | :---: |
| Reel | A | 2,000 | D26Z |
|  | E | 2,000 | D27Z |
| Ammo | M | 2,000 | D $74 Z$ |
|  | P | 2,000 | D75Z | | Unit weight |
| :--- |
| Reel weight with components <br> Ammo weight with components <br> Max quantity per intermediate box <br> $=1.22 \mathrm{gm}$ <br> $=1.04 \mathrm{~kg}$ <br> $=10,000$ <br> kg units |


(TO-92) BULK PACKING INFORMATION

| $\begin{aligned} & \hline \text { EOL } \\ & \text { CODE } \\ & \hline \end{aligned}$ | DESCRIPTION | LEADCLIP DIMENSION | QUANTITY |
| :---: | :---: | :---: | :---: |
| J182 | TO-18 OPTION STD | NO LEAD CLIP | 2.0 K/BOX |
| J05z | TO-5 OPTION STD | NO LEAD CLIP | $1.5 \mathrm{~K} / \mathrm{BOX}$ |
| NO EOL | TO-92 STANDARD STRAIGHT FOR: PKG 92, 94 (NON PROELECTRON SERIES), 96 | NO LEADCLIP | 2.0 K / BOX |
| L342 | TO-92 STANDARD STRAIGHT FOR: PKG 94 (PROELECTRON SERIES BCXXX, BFXXX, BSRXXX), 97, 98 | NO LEADCLIP | 2.0 K / BOX |

BULK OPTION
See Bulk Packing
Information table


## TO-92 Tape and Reel Data, continued

## TO-92 Reeling Style

## Configuration: Figure 2.0



Style "A", D26Z, D70Z (s/h)

## TO-92 Radial Ammo Packaging

## Configuration: Figure 3.0




Style "E", D27Z, D71Z (s/h)


## TO-92 Tape and Reel Data, continued

## TO-92 Tape and Reel Taping

Dimension Configuration: Figure 4.0


## TO－92 Package Dimensions <br> FAIRCHILD

SEMICロNロレСTロR

## TO－92（FS PKG Code 92，94，96）



Scale 1：1 on letter size paper Dimensions shown below are in： inches［millimeters］
Part Weight per unit（gram）： 0.1977


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Definition of Terms

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| :--- | :--- | :--- |
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